



LIS332AR

MEMS motion sensor: 3-axis $\pm 2\text{ g}$ analog-output ultracompact accelerometer

Features

- Single voltage supply operation
- $\pm 2\text{ g}$ full-scale
- High stability over temperature
- Ratiometric output voltage
- Power-down mode
- Embedded self-test
- 10000 g high shock survivability
- ECOPACK® RoHS and “Green” compliant (see [Section 7](#))

Applications

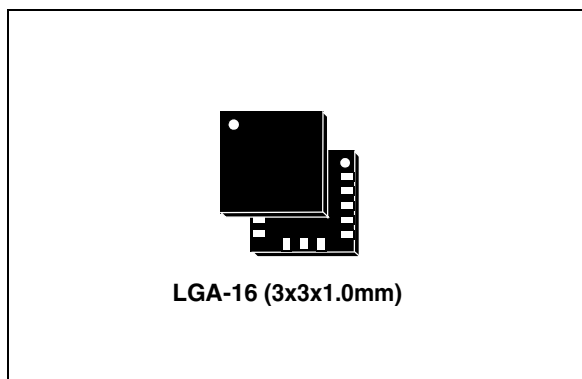
- Tilting applications
- Free-fall detection
- Gaming
- Anti-theft systems
- Inertial navigation and motion tracking

Description

The LIS332AR is a miniaturized low-power 3-axis linear accelerometer belonging to the “nano” family of ST motion sensors. It includes a sensing element and an IC interface to provide an analog signal to the external world.

The sensing element, capable of detecting the acceleration, is manufactured using a dedicated process developed by ST to produce motion sensors and actuators in silicon.

The IC interface is manufactured using a CMOS process that allows the design of a dedicated



circuit which is trimmed to better match the sensing element characteristics.

The LIS332AR has a full-scale of $\pm 2\text{ g}$, and is capable of measuring accelerations over a maximum bandwidth of 2.0 kHz. The device bandwidth may be reduced by using external capacitors. The self-test capability allows the user to check the functioning of the sensor in the final application.

ST is already in the field with several hundred million sensors which have received excellent acceptance from the market in terms of quality, reliability and performance.

The LIS332AR is provided in a plastic land grid array (LGA) package.

Several years ago ST successfully pioneered the use of this package for accelerometers. Today, ST has the widest manufacturing capability and strongest expertise in the world for production of sensors in plastic LGA packages.

Table 1. Device summary

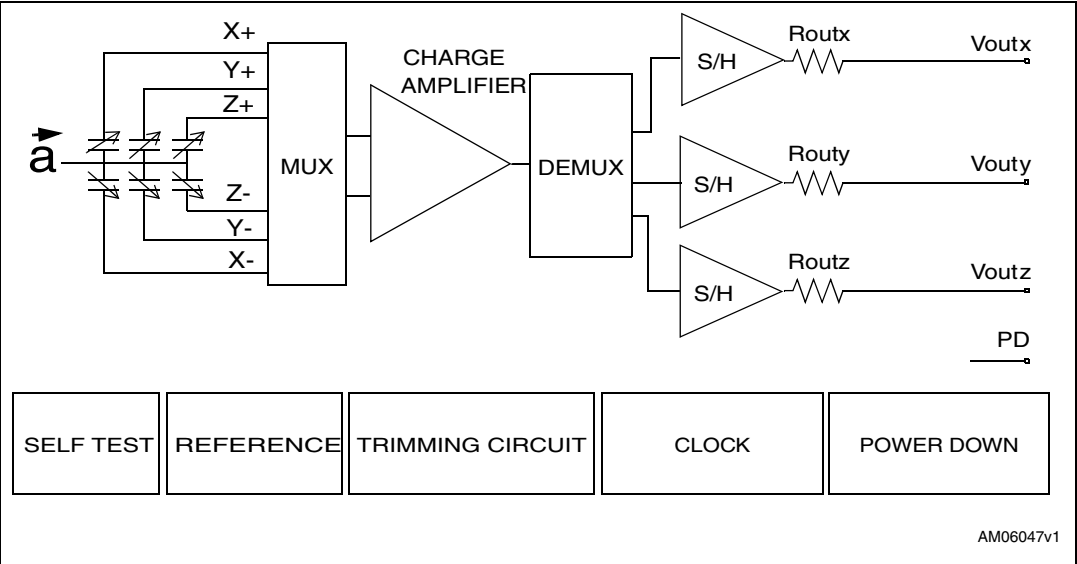
Order code	Temperature range [°C]	Package	Packing
LIS332AR	-40 to +85	LGA-16	Tray
LIS332ARTR	-40 to +85	LGA-16	Tape and reel

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1 Block diagram and pin description

Figure 1. Block diagram



1.1 Pin connections and description

Figure 2. Pin connection

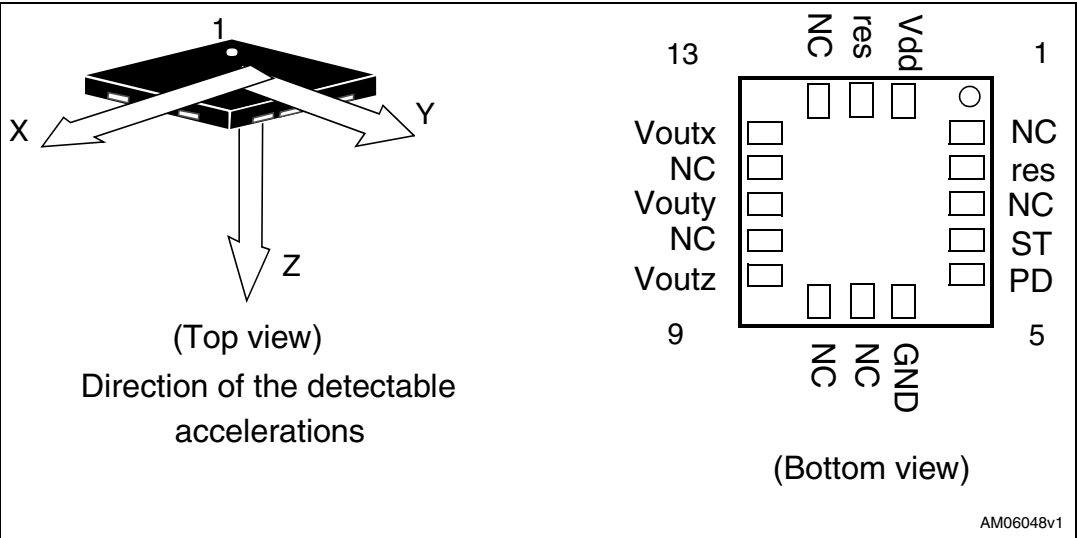


Table 2. Pin description

Pin #	Pin name	Function
1	NC	Internally not connected
2	res	Connect to Vdd
3	NC	Internally not connected
4	ST	Self-test (logic 0: normal mode; logic 1: self-test mode)
5	PD	Power-down (logic 0: normal mode; logic 1: power-down mode)
6	GND	0 V supply
7	NC	Internally not connected
8	NC	Internally not connected
9	Voutz	Output voltage Z channel
10	NC	Internally not connected
11	Vouty	Output voltage Y channel
12	NC	Internally not connected
13	Voutx	Output voltage X channel
14	NC	Internally not connected
15	res	Connect to Vdd
16	Vdd	Power supply

2 Mechanical and electrical specifications

2.1 Mechanical characteristics

@ Vdd=3 V, T=25 °C unless otherwise noted^(a).

Table 3. Mechanical characteristics

Symbol	Parameter	Test condition	Min.	Typ. ⁽¹⁾	Max.	Unit
Ar	Acceleration range ⁽²⁾			±2		g
So	Sensitivity ⁽³⁾		0.2*Vdd -5%	0.2*Vdd	0.2*Vdd + 5%	V/g
SoDr	Sensitivity change vs. temperature	Delta from +25 °C		±0.01		%/°C
Voff	Zero-g level ⁽⁴⁾	T=25 °C	Vdd/2-6%	Vdd/2	Vdd/2+6%	V
OffDr	Zero-g level change vs. temperature	Delta from +25 °C		±0.2		mg/°C
NL	Non linearity ⁽⁴⁾	Best fit straight line		±0.5		% FS
CrossAx	Cross-axis ⁽⁵⁾			±2		%
An	Acceleration noise density	Vdd=3 V		100		μg/√Hz
Vt	Self-test output voltage change ^{(6),(7)}	T=25 °C Vdd=3 V X axis	60		700	mV
		T=25 °C Vdd=3 V Y axis	60		700	mV
		T=25 °C Vdd=3 V Z axis	60		700	mV
Fres	Sensing element resonant frequency ⁽⁸⁾	All axes	2.0			kHz
Top	Operating temperature range		-40		+85	°C
Wh	Product weight			30		mgram

- Typical specifications are not guaranteed
- Guaranteed by wafer level test and measurement of initial offset and sensitivity
- Zero-g level and sensitivity are ratiometric to supply voltage
- Guaranteed by design
- Contribution to the measured output of an inclination/acceleration along any perpendicular axis
- "Self-test output voltage change" is defined as $V_{out}(V_{st=logic\ 1}) - V_{out}(V_{st=logic\ 0})$
- "Self-test output voltage change" varies cubically with supply voltage
- Minimum resonance frequency $F_{RES}=2.0$ kHz. Sensor bandwidth= $1/(2*\pi*32k\Omega*C_{LOAD})$, with $C_{LOAD}>2.5$ nF

a. The product is factory calibrated at 3 V. The operational power supply range is specified in [Table 4](#). Since the device is ratiometric, Voff, So and Vt parameters vary with supply voltage.

2.2 Electrical characteristics

@ Vdd=3 V, T=25 °C unless otherwise noted^(b).

Table 4. Electrical characteristics

Symbol	Parameter	Test condition	Min.	Typ. ⁽¹⁾	Max.	Unit
Vdd	Supply voltage		2.16	3	3.6	V
Idd	Supply current	Mean value PD pin connected to GND		0.3		mA
IddPdn	Supply current in power-down mode	PD pin connected to Vdd		1		μA
Vst	Self-test input	Logic 0 level at Vdd=3 V	0		0.2*Vdd	V
Vpd	Power-down input	Logic 1 level at Vdd=3 V	0.8*Vdd		Vdd	
Rout	Output impedance of Voutx, Vouty, Voutz			32		kΩ
Cload	Capacitive load drive for Voutx, Vouty, Voutz ⁽²⁾		2.5			nF
Ton	Turn-on time at exit from power-down mode	C _{LOAD} in μF		160*C _{LOAD} +0.3		ms
Top	Operating temperature range		-40		+85	°C

1. Typical specifications are not guaranteed

2. Minimum resonance frequency F_{RES}=2.0 kHz. Device bandwidth=1/(2*π*32kΩ*C_{LOAD}), with C_{LOAD}>2.5 nF

b. The product is factory calibrated at 3 V.

3 Absolute maximum ratings

Stresses above those listed as “Absolute maximum ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device under these conditions is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

Table 5. Absolute maximum ratings

Symbol	Ratings	Maximum value	Unit
V _{DD}	Supply voltage	-0.3 to 6	V
V _{IN}	Input voltage on any control pin (PD, ST)	-0.3 to V _{DD} +0.3	V
A _{POW}	Acceleration (any axis, powered, V _{DD} =3 V)	3000 g for 0.5 ms	
		10000 g for 0.1 ms	
A _{UNP}	Acceleration (any axis, not powered)	3000 g for 0.5 ms	
		10000 g for 0.1 ms	
T _{STG}	Storage temperature range	-40 to +125	°C
ESD	Electrostatic discharge protection	4 (HBM)	kV
		1.5 (CDM)	kV
		200 (MM)	V

Note: Supply voltage on any pin should never exceed 6.0 V.



This is a mechanical shock sensitive device, improper handling can cause permanent damage to the part



This is an ESD sensitive device, improper handling can cause permanent damage to the part

4 Terminology

4.1 Sensitivity

Sensitivity describes the gain of the sensor and can be determined by applying 1 *g* acceleration to it. Because the sensor can measure DC accelerations, this can be done easily by pointing the selected axis towards the ground, noting the output value, rotating the sensor 180 degrees (pointing towards the sky) and noting the output value again. By doing so, a ± 1 *g* acceleration is applied to the sensor. Subtracting the larger output value from the smaller one, and dividing the result by 2, produces the actual sensitivity of the sensor. This value changes very little over temperature (see sensitivity change vs. temperature) and over time. The sensitivity tolerance describes the range of sensitivities of a large number of sensors.

4.2 Zero-*g* level

Zero-*g* level describes the actual output signal if there is no acceleration present. A sensor in a steady state on a horizontal surface will measure 0 *g* on both the X and Y axes, whereas the Z axis will measure 1 *g*. Ideally, the output for a 3 V powered sensor is $V_{dd}/2 = 1500$ mV. A deviation from the ideal 0 *g* level (1500 mV, in this case) is called Zero-*g* offset. Offset is to some extent a result of stress to the MEMS sensor and therefore the offset can slightly change after mounting the sensor onto a printed circuit board or exposing it to extensive mechanical stress. Offset changes little over temperature (see “Zero-*g* level change vs. temperature” in [Table 3: Mechanical characteristics](#)). The Zero-*g* level of an individual sensor is also very stable over its lifetime. The Zero-*g* level tolerance describes the range of Zero-*g* levels of a group of sensors.

4.3 Self-test

Self-test (ST) allows the checking of sensor functionality without moving it. The self-test function is off when the ST pin is connected to GND. When the ST pin is tied to V_{dd}, an actuation force is applied to the sensor, simulating a definite input acceleration. In this case, the sensor outputs exhibit a voltage change in their DC levels. When ST is activated, the device output level is given by the algebraic sum of the signals produced by the acceleration acting on the sensor and by the electrostatic test-force. If the output signals change within the amplitude specified in [Table 3](#), then the sensor is working properly and the parameters of the interface chip are within the defined specifications.

4.4 Output impedance

Output impedance describes the resistor inside the output stage of each channel. This resistor is part of a filter consisting of an external capacitor of at least 2.5 nF and the internal resistor. Due to the resistor level, only small inexpensive external capacitors are needed to generate low corner frequencies. When interfacing with an ADC, it is important to use high input impedance input circuitries to avoid measurement errors. Note that the minimum load capacitance forms a corner frequency close to the resonant frequency of the sensor. In general, the smallest possible bandwidth for a particular application should be chosen to obtain the best results.

5 Functionality

The LIS332AR is a 3-axis ultracompact, low-power, analog output accelerometer packaged in an LGA package. The complete device includes a sensing element and an IC interface capable of taking information from the sensing element and providing an analog signal to the external world.

5.1 Sensing element

A proprietary process is used to create a surface micro-machined accelerometer. The technology allows the creation of suspended silicon structures which are attached to the substrate at several points called “anchors” and are free to move in the direction of the sensed acceleration. To be compatible with traditional packaging techniques, a cap is placed on top of the sensing element to prevent blocking of the moving parts during the moulding phase of plastic encapsulation.

When an acceleration is applied to the sensor, the proof mass shifts from its nominal position, causing an imbalance in the capacitive half-bridge. This imbalance is measured using charge integration in response to a voltage pulse applied to the sense capacitor.

At steady state, the nominal value of the capacitors are a few pF, and when an acceleration is applied the maximum variation of the capacitive load is in the fF range.

5.2 IC interface

The complete signal processing utilizes a fully differential structure, while the final stage converts the differential signal into a single-ended signal to be compatible with external applications.

The first stage is a low-noise capacitive amplifier that implements a correlated double sampling (CDS) at its output to cancel the offset and the 1/f noise. The signal produced is then sent to three different S&Hs, one for each channel, and made available to the outside.

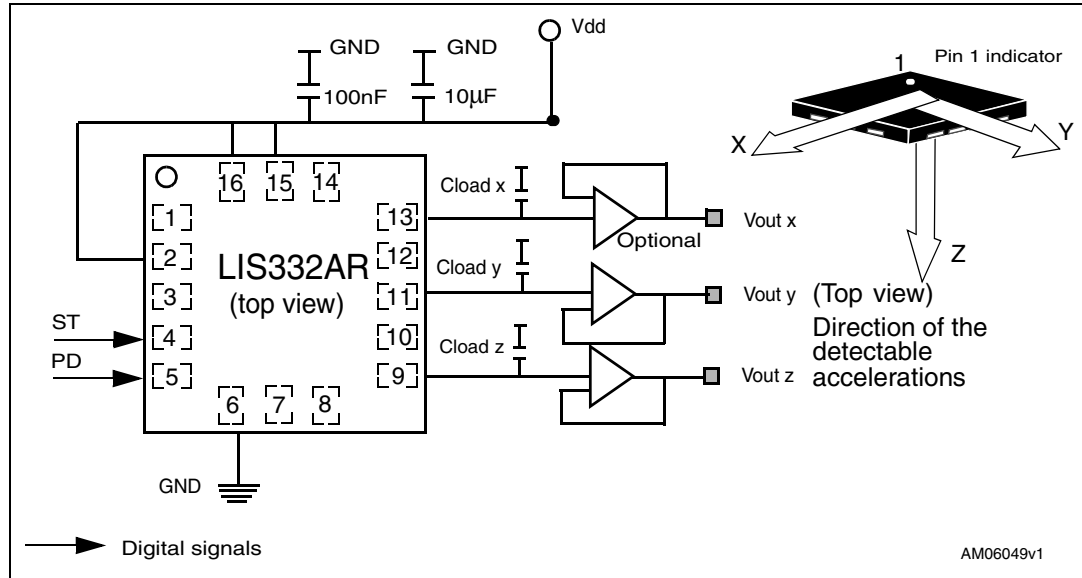
All the analog parameters (output offset voltage and sensitivity) are ratiometric to the voltage supply. Increasing or decreasing the voltage supply, the sensitivity and the offset increases or decreases linearly. This feature provides for cancellation of the error related to the voltage supply along an analog-to-digital conversion chain.

5.3 Factory calibration

The IC interface is factory-calibrated for sensitivity (S_o) and Zero- g level (V_{off}). The trimming values are stored in the device in a non-volatile structure. Any time the device is turned on, the trimming parameters are downloaded to the registers to be employed during normal operation. This allows the user to use the device without further calibration.

6 Application hints

Figure 3. LIS332AR electrical connection



Power supply decoupling capacitors (100 nF ceramic or polyester + 10 µF aluminum) should be placed as near as possible to the device (common design practice).

The LIS332AR allows band limiting of Voutx, Vouty and Voutz through the use of external capacitors. The recommended frequency range spans from DC up to 2.0 kHz. Capacitors must be added at the output pins to implement low-pass filtering for anti-aliasing and noise reduction. The equation for the cut-off frequency (f_t) of the external filters is:

$$f_t = \frac{1}{2\pi \cdot R_{out} \cdot C_{load}(x, y, z)}$$

Taking into account that the internal filtering resistor (R_{out}) has a nominal value of 32 kΩ, the equation for the external filter cut-off frequency may be simplified as follows:

$$f_t = \frac{5\mu F}{C_{load}(x, y, z)} [Hz]$$

The tolerance of the internal resistor can vary $\pm 15\%$ (typ) from its nominal value of 32 kΩ; thus the cut-off frequency will vary accordingly. A minimum capacitance of 2.5 nF for C_{LOAD} (x, y, z) is required.

Table 6. Filter capacitor selection, C_{LOAD} (x,y,z)

Cut-off frequency	Capacitor value
1 Hz	5 μ F
10 Hz	0.5 μ F
20 Hz	250 nF
50 Hz	100 nF
100 Hz	50 nF
200 Hz	25 nF
500 Hz	10 nF

6.1 Soldering information

The LGA package is compliant with the ECOPACK[®], RoHs and “Green” standard. It is qualified for soldering heat resistance according to JEDEC J-STD-020C.

Leave “pin 1 Indicator” unconnected during soldering.

Land pattern and soldering recommendations are available at www.st.com

6.2 Output response vs. orientation

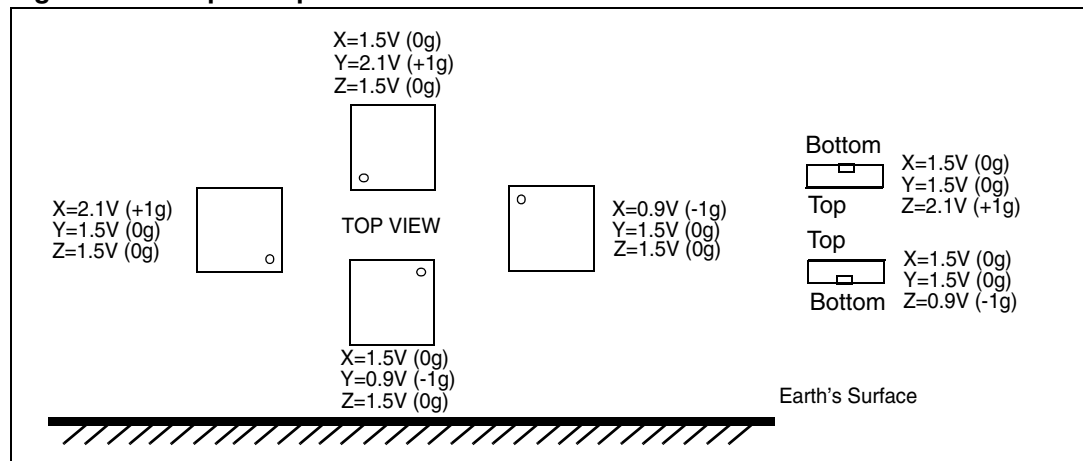
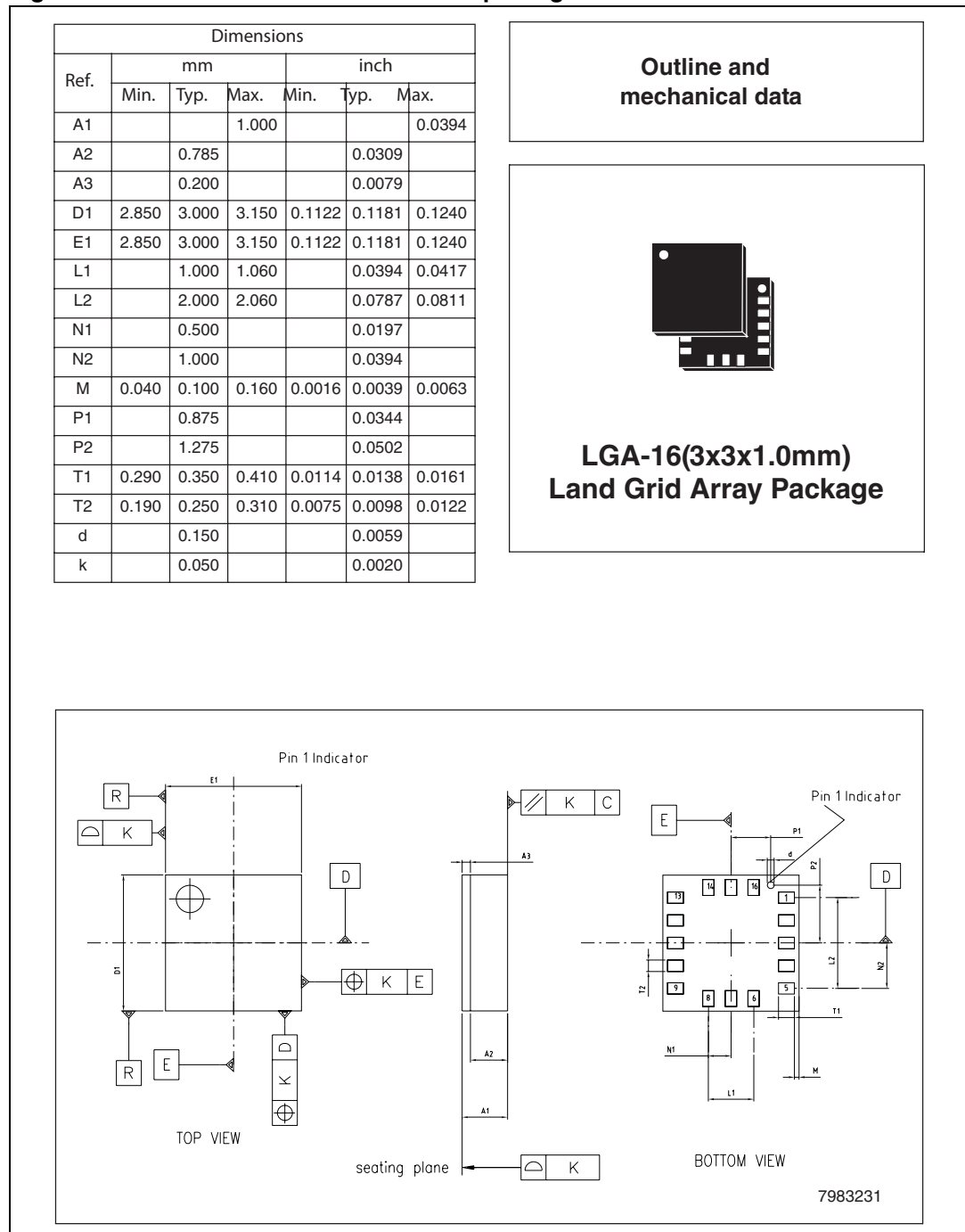
Figure 4. Output response vs. orientation

Figure 4 refers to the LIS332AR powered at 3 V.

7 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Figure 5. LGA-16: mechanical data and package dimensions



8 Revision history

Table 7. Document revision history

Date	Revision	Changes
02-Feb-2010	1	Initial release.

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